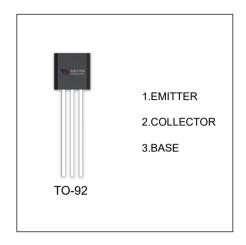


BC556 / BC557 / BC558 TRANSISTOR (PNP)

FEATURES

- High Voltage
- Complement to BC546,BC547,BC548



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
BC556	TO-92	Bulk	1000pcs/Bag
BC556-TA	TO-92	Tape	2000pcs/Box
BC557	TO-92	Bulk	1000pcs/Bag
BC557-TA	TO-92	Tape	2000pcs/Box
BC558	TO-92	Bulk	1000pcs/Bag
BC558-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS (T_a =25 $^{\circ}$ C unless otherwise noted)

Symbol	Parameter		Value	Unit
		BC556	-80	
V _{CBO}	Collector-Base Voltage	BC557	-50	V
		BC558	-30	
		BC556	-65	
V _{CEO}	Collector-Emitter Voltage	BC557	-45	V
		BC558	-30	
V _{EBO}	Emitter-Base Voltage		-5	V
Ic	Collector Current-Continuous		-0.1	Α
Pc	Collector Power Dissipation		625	mW
R _{θJA}	Thermal Resistance from Junction to Ambient		200	°C/W
T _J ,T _{stg}	Operation Junction and Storage Temperature Range		-55~+150	℃



Parameter		Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base	BC556			-80			
	BC557	$V_{(BR)CBO}$ $I_C = -0.1 \text{mA}, I_E = 0$	$I_C = -0.1 \text{mA}, I_E = 0$	-50			V
breakdown voltage	BC558			-30			
Collector-emitter	BC556	V _{(BR)CEO}	I _C =-2mA,I _B =0	-65			V
	BC557			-45			
breakdown voltage	BC558			-30			
Emitter-base breakdown voltage		V _{(BR)EBO}	I _E =-100μA,I _C =0	-5			V
	BC556	I _{CBO}	V _{CB} =-70V,I _E =0			-0.1	μΑ
Collector cut-off current	BC557		V _{CB} =-45V,I _E =0			-0.1	μΑ
	BC558		V _{CB} =-25V,I _E =0			-0.1	μΑ
Collector cut-off current	BC556		V _{CE} =-60V,I _B =0			-0.1	μA
	BC557	I _{CEO}	V _{CE} =-40V,I _B =0			-0.1	μA
	BC558		V _{CE} =-25V,I _B =0			-0.1	μA
Emitter cut-off current		I _{EBO}	V _{EB} =-5V,I _C =0			-0.1	μΑ
DC current gain		h _{FE} *	V_{CE} =-5V, I_{C} =-2mA	120		800	
Collector-emitter saturation voltage V _{CE(s}		\/	I _C =-10mA,I _B =-0.5mA			-0.3	V
		V CE(sat)	I _C =-100mA,I _B =-5mA			-0.65	V
Dan anith and the state of the state of		\/	I _C =-10mA,I _B =-0.5mA			-0.8	V
base-emitter saturation vo	r saturation voltage V _{BE(sat)}		I _C =-100mA,I _B =-5mA			-1	V
Paga amittar valtaga		.,	V_{CE} =-5V, I_{C} =-2mA	-0.55		-0.7	V
Base-emitter voltage		V _{BE}	V _{CE} =-5V, I _C =-10mA			-0.82	V
Collector output capacitance		C _{ob}	V _{CB} =-10V,I _E =0, f=1MHz			6	pF
Transition frequency	BC556	f _T	Vce=-5V,lc=-10mA, f=100MHz		150		MHz
	BC557				150		MHz
	BC558	1			150		MHz

CLASSIFICATION of h_{FE}

RANK	Α	В	С
RANGE	120-220	180-460	420-800